

# 74VHC132 Quad 2-Input NAND Schmitt Trigger

## **General Description**

The 'VHC132 is an advanced high speed CMOS 2-input NAND Schmitt Trigger Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Pin configuration and function are the same as the VHC00 but the inputs have hysteresis between the positive-going and negative-going input thresholds, which are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals, thus providing greater noise margin then conventional gates. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two

supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **Features**

- High noise immunity
- Power down protection
- Low power
- Low noise
- Balanced propagation delays
- Pin and function compatible with 74HC132

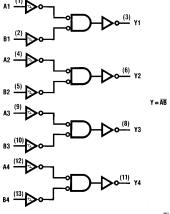
Commercial	Package Number	Package Description			
74VHC132M	M14A	14-Lead Molded JEDEC SOIC			
74VHC132SJ	M14D	14-Lead Molded EIAJ SOIC			
74VHC132MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP			
74VHC132N	N14A	14-Lead Molded DIP			

**Note:** Surface mount packages are also available on Tape and Reel. Specifiy by appending the suffix letter "X" to the ordering code.

#### **Connection Diagram**

#### Pin Assignment for DIP. TSSOP and SOIC VCC R4 R3 **A3 Y3** 10 14 12 B2 **GND** A 1 В1 Y1 A2 Y2 TL/F/12124-1

## **Logic Diagram**



#### Absolute Maximum Ratings (Note 1)

Supply Voltage (V<sub>CC</sub>) -0.5V to +7.0V DC Input Voltage (V<sub>IN</sub>)  $-0.5\mbox{V}$  to  $+7.0\mbox{V}$ DC Output Voltage (V<sub>OUT</sub>) - 0.5V to V $_{\rm CC}$  + 0.5V Input Diode Current (I<sub>IK</sub>)  $-20 \, \text{mA}$ Output Diode Current (I<sub>OK</sub>)  $\pm\,20~mA$ DC Output Current (I<sub>OUT</sub>)  $\pm\,$ 25 mA DC V<sub>CC</sub>/GND Current (I<sub>CC</sub>)  $\pm\,$ 50 mA  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ Storage Temperature (T<sub>STG</sub>)

Lead Temperature (T<sub>L</sub>) (Soldering, 10 seconds) 260°C Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation outside databook specifications.

# Recommended Operating Conditions

### **DC Characteristics for 'VHC Family Devices**

			74VHC		74VHC		Units				
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Conditions			
			Min	Тур	Max	Min	Max				
V <sub>P</sub>	Positive Threshold Voltage	3.0 4.5 5.5			2.20 3.15 3.85		2.20 3.15 3.85	V			
V <sub>N</sub>	Negative Threshold Voltage	3.0 4.5 5.5	0.90 1.35 1.65			0.90 1.35 1.65		٧			
V <sub>H</sub>	Hysteresis Output Voltage	3.0 4.5 5.5	0.30 0.40 0.50		1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	٧			
V <sub>OH</sub>	High Level Output Voltage	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50 \mu A$	
		3.0 4.5	2.58 3.94			2.48 3.80		٧		$I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$	
V <sub>OL</sub>	Low Level Output Voltage	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50 \mu\text{A}$	
		3.0 4.5			0.36 0.36		0.44 0.50	٧		$I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$	
I <sub>IN</sub>	Input Leakage Current	0-5.5			±0.1		± 1.0	μΑ	V <sub>IN</sub> = 5.5V or GND		
Icc	Quiescent Supply Current	5.5			2.0		20.0	μΑ	$V_{IN} = V_{CC}$ or GND		

# DC Characteristics for 'VHC Family Devices:

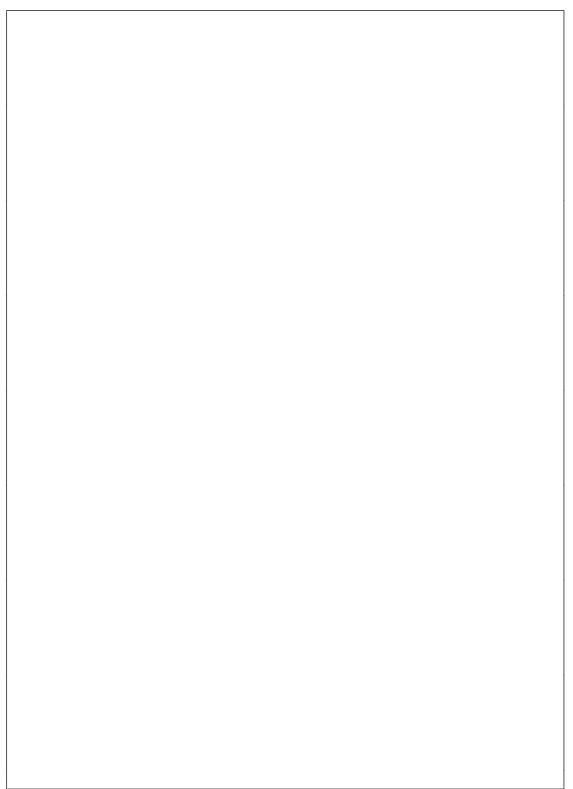
Symbol	Parameter	V <sub>CC</sub> (V)		/HC 25°C	Units	Conditions
-			Тур	Limit		
*V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	5.0	0.3	0.8	V	$C_L = 50 \text{ pF}$
*V <sub>OLV</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	5.0	-0.3	-0.8	V	$C_L = 50  pF$
*V <sub>IHD</sub>	Maximum High Level Dynamic Input Voltage	5.0		3.5	V	$C_L = 50  pF$
*V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	$C_L = 50  pF$

<sup>\*</sup>Parameter guaranteed by design

# **AC Electrical Characteristics for 'VHC Family Devices**

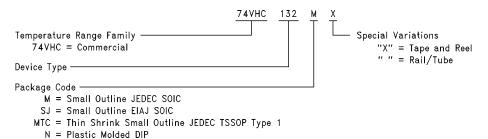
	Parameter	V <sub>CC</sub> (V)	74VHC T <sub>A</sub> = 25°C			74VHC T <sub>A</sub> = -40°C to +85°C		Units	Conditions
Symbol									
			Min	Тур	Max	Min	Max		
t <sub>PHL</sub> ,	t <sub>PHL</sub> , Propagation Delay	3.3 ±0.3		6.1	11.9	1.0	14.0	ns	$C_L = 15 pF$
t <sub>PHL</sub>				8.0	15.4	1.0	17.5		C <sub>L</sub> = 50 pF
		5.0 ±0.5		3.9	7.7	1.0	9.0	ns	$C_L = 15 pF$
				5.9	9.7	1.0	11.0		$C_L = 50 pF$
C <sub>IN</sub>	Input Capacitance			4	10		10	pF	V <sub>CC</sub> = Open
C <sub>PD</sub>	Power Dissipation Capacitance			16				pF	(Note 1)

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation:  $I_{CC}$  (opr.) =  $C_{PD}$  \*  $V_{CC}$  \*  $I_{IN}$  +  $I_{CC}$ /4 (per gate)



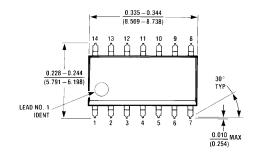
#### **Ordering Information**

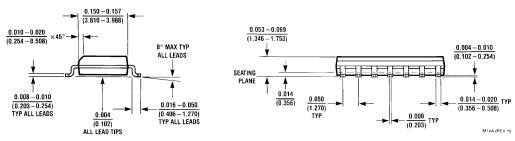
The device number is used to form part of a simplified purchasing code, where the package type and temperature range are defined as follows:



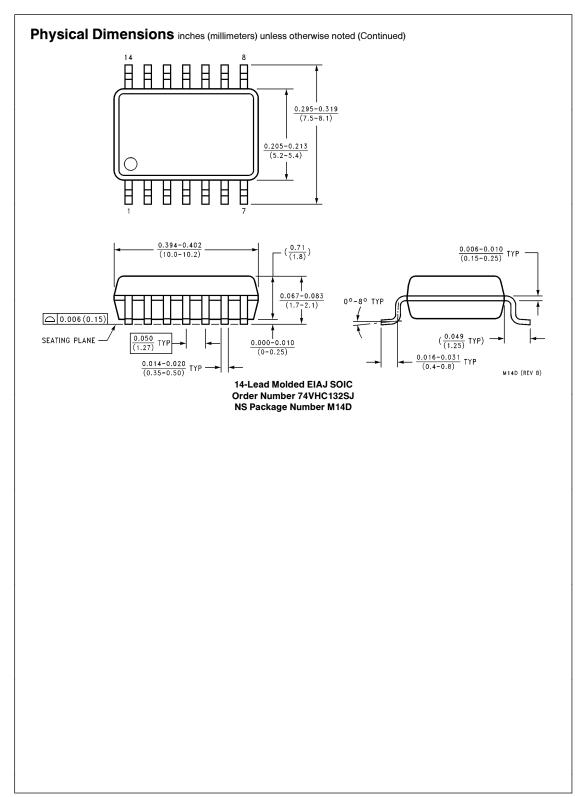
TL/F/12124-3

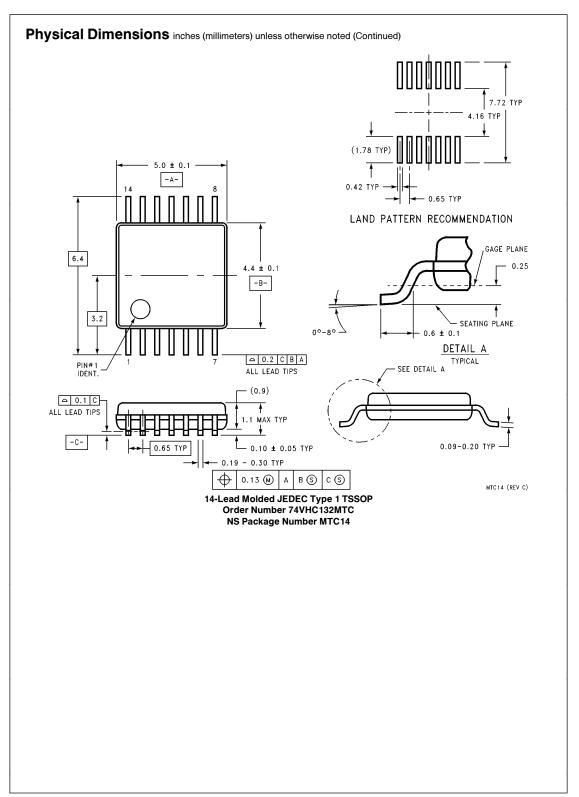
#### Physical Dimensions inches (millimeters)



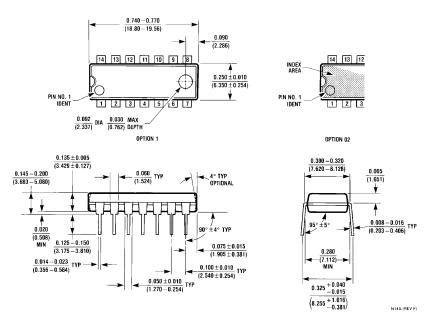


14-Lead Molded JEDEC SOIC Order Number 74VHC132M NS Package Number M14A





#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded DIP Order Number 74VHC132N NS Package Number N14A

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**National Semiconductor** National Semiconducto Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018

http://www.national.com

**National Semiconductor** Europe

Fax: +49 (0) 180-530 85 86 Fax: +49 (0) 180-530 so so Email: europe.support@nsc.com Deutsch Tel: +49 (0) 180-530 85 85 English Tel: +49 (0) 180-532 78 32 Français Tel: +49 (0) 180-532 95 58 Italiano Tel: +49 (0) 180-534 16 80 **National Semiconductor** Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960

Japan Ltd.
Tel: 81-043-299-2308
Fax: 81-043-299-2408

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